

INCHANGE SEMICONDUCTOR

isc N-Channel Mosfet Transistor

BUZ12A

• FEATURES

- Static Drain-Source On-Resistance
 - : R_{DS(on)} = 0.035 Ω (Max)
- SOA is Power Dissipation Limited
- · High input impedance
- High speed switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

Designed for applications such as switching regulators, switching converters, motor drivers, relay drivers and drivers for high power bipolar switching transistors requiring high speed and low gate drive power .

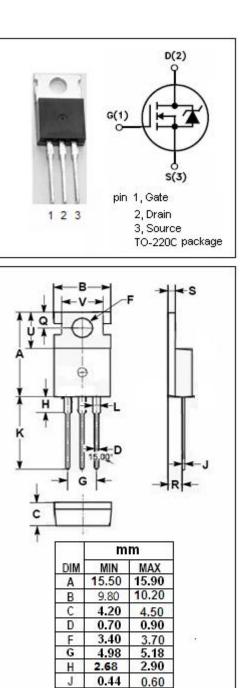
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	50	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-continuous@ TC=44°C	42	А
I _{DM}	Drain Current-Single Plused	168	А
P _{tot}	Total Dissipation@TC=25°C	125	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	e,Junction to Case 1	
R _{th j-a}	Thermal Resistance, Junction to Ambient	75	°C/W

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12.80 1.20 2.70

2.30

1.29

6.45

8.66

13.40

2.90

2.70

1.35

6.65

8.86



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =0.25mA	50			V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	2.1		4.0	V
V_{SD}	Diode Forward On-voltage	I _S = 84A ;V _{GS} = 0			2.2	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 32A			0.035	Ω
Igss	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =50V; V _{GS} = 0			1	μA
Gfs	Forward Transconductance	V _{DS} = 25V; I _D =32A	12			S
t _{d(on)}	Turn-on Delay Time	V _{GS} =10V;			50	
tr	Rise Time	I _D =3A;			130	
$t_{d(off)}$	Turn-off Delay Time	V _{DD} =30V; R _{GS} =50 Ω			280	ns
t _f	Fall Time				180	

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